

TO-92

Pin Definition:

1. Emitter
2. Collector
3. Base

PRODUCT SUMMARY

BV_{CEO}	700V
BV_{CBO}	1500V
I_C	1A
V_{CE(SAT)}	1.0V @ I _C / I _B = 0.5A / 0.1A

Features

- Very High Voltage
- High Speed Switching

Structure

- Silicon Triple Diffused Type
- NPN Silicon Transistor

Ordering Information

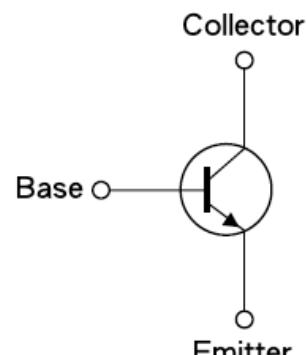
Part No.	Package	Packing
TSC5401CT B0	TO-92	1Kpcs / Bulk
TSC5401CT B0G	TO-92	1Kpcs / Bulk
TSC5401CT A3	TO-92	2Kpcs / Ammo
TSC5401CT A3G	TO-92	2Kpcs / Ammo

Note: "G" denote for Green Product

Absolute Maximum Rating (Ta = 25°C unless otherwise noted)

Parameter	Symbol	Limit	Unit
Collector-Base Voltage	V _{CBO}	1500V	V
Collector-Emitter Voltage	V _{CEO}	700V	V
Emitter-Base Voltage	V _{EBO}	7	V
Collector Current	DC	1	A
	Pulse	2	
Base Current	DC	0.5	A
	Pulse	1	
Total Power Dissipation	P _D	10	W
Operating Junction Temperature	T _J	+150	°C
Operating Junction and Storage Temperature Range	T _{STG}	- 55 to +150	°C

Note: Single Pulse. P_w = 300uS, Duty ≤2%

Block Diagram


Electrical Specifications (Ta = 25°C unless otherwise noted)

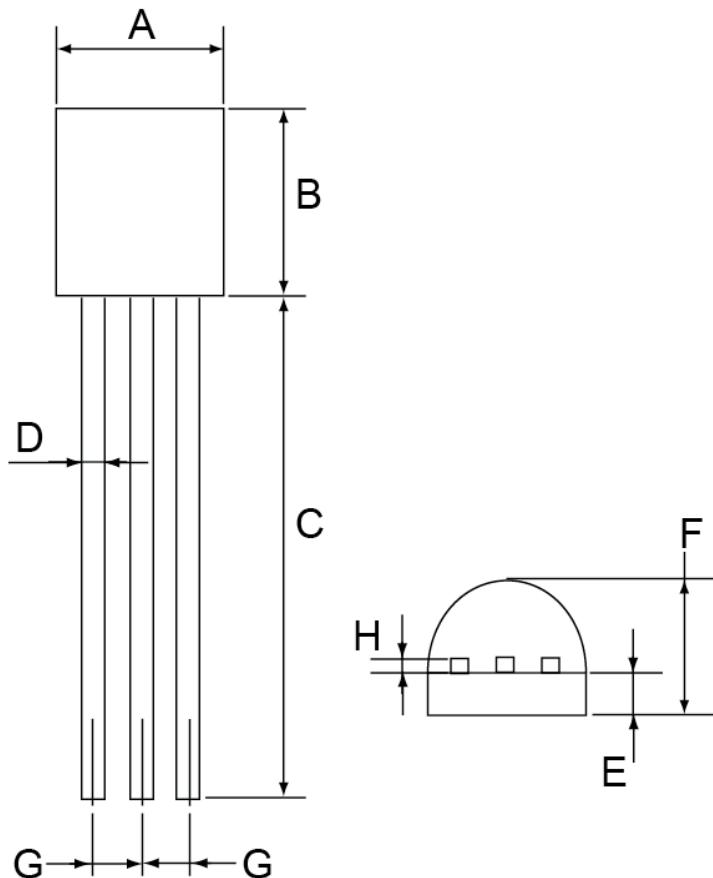
Parameter	Conditions	Symbol	Min	Typ	Max	Unit
Static						
Collector-Base Voltage	I _C = 1mA, I _B = 0	BV _{CBO}	1500	--	--	V
Collector-Emitter Breakdown Voltage	I _C = 5mA, I _E = 0	BV _{CEO}	700	--	--	V
Emitter-Base Breakdown Voltage	I _E = 1mA, I _C = 0	BV _{EBO}	7	--	--	V
Collector Cutoff Current	V _{CE} = 700V, I _B = 0	I _{CEO}	--	--	10	uA
Collector Cutoff Current	V _{CB} = 1300V, I _E = 0	I _{CBO}	--	--	1	mA
Emitter Cutoff Current	V _{EB} = 7V, I _C = 0	I _{EBO}	--	--	10	uA
Collector-Emitter Saturation Voltage	I _C = 0.2A, I _B = 0.04A	V _{CE(SAT)} 1	---	--	0.3	V
Collector-Emitter Saturation Voltage	I _C = 0.5A, I _B = 0.1A	V _{CE(SAT)} 2	---	--	1.0	V
Base-Emitter Saturation Voltage	I _C = 0.5A, I _B = 0.1A	V _{BE(SAT)}	--	--	1.2	V
DC Current Gain	V _{CE} = 5V, I _C = 10mA	h _{FE}	20	--	45	
	V _{CE} = 5V, I _C = 500mA		5	--		
	V _{CE} = 5V, I _C = 1A		2	--	--	

Dynamic
Resistive Load Switching Time (Ratings)

Rise Time	V _{CC} = 400V, I _C = 0.5A, I _{B1} = 0.1, I _{B2} = -0.2A, t _P = 25uS	t _r		0.4	0.8	uS
Storage Time		t _{STG}	--	1.5	3	uS
Fall Time		t _f	--	0.25	0.4	uS

Note: pulse test: pulse width ≤300uS, duty cycle ≤2%

TO-92 Mechanical Drawing



TO-92 DIMENSION				
DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	4.30	4.70	0.169	0.185
B	4.30	4.70	0.169	0.185
C	13.53 (typ)		0.532 (typ)	
D	0.39	0.49	0.015	0.019
E	1.18	1.28	0.046	0.050
F	3.30	3.70	0.130	0.146
G	1.27	1.31	0.050	0.051
H	0.33	0.43	0.013	0.017

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